

## Features

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

$I_{F(AV)}$	<b>1230A</b>
$V_{RRM}$	<b>200 ~ 1400V</b>
$I_{FSM}$	<b>11 kA</b>
$I^2t$	<b>605 10<sup>3</sup>A<sup>2</sup>S</b>

## Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T <sub>j</sub> (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled, T <sub>C</sub> =85°C	190			1230	A
$V_{RRM}$	Repetitive peak reverse voltage	tp=10ms	190	200		1400	V
$I_{RRM}$	Repetitive peak current	at V <sub>RRM</sub>	190			30	mA
$I_{FSM}$	Surge forward current	10ms half sine wave	190			11	kA
$I^2t$	I <sup>2</sup> t for fusing coordination	V <sub>R</sub> =0.6V <sub>RRM</sub>				605	A <sup>2</sup> s*10 <sup>3</sup>
$V_{FO}$	Threshold voltage		190			0.95	V
r <sub>F</sub>	Forward slope resistance					0.31	mΩ
$V_{FM}$	Peak forward voltage	I <sub>FM</sub> =1200A, F=7.0kHz	25			1.80	V
Q <sub>rr</sub>	Recovery charge	I <sub>FM</sub> =1000A, tp=4000μs, di/dt=-20A/μs, V <sub>R</sub> =100V	190		1600		μC
R <sub>th(j-c)</sub>	Thermal resistance Junction to case	D.C. double side cooled Clamping force 7.0kN				0.045	°C/W
R <sub>th(c-h)</sub>	Thermal resistance case to heat sink					0.010	
F <sub>m</sub>	Mounting force			5.3		10	kN
T <sub>vj</sub>	Junction temperature			-40		190	°C
T <sub>stg</sub>	Stored temperature			-40		190	°C
W <sub>t</sub>	Weight				80		g
Outline	P33						

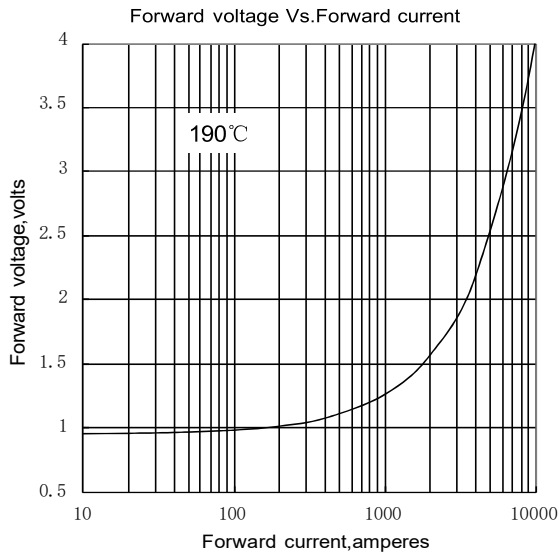


Fig1

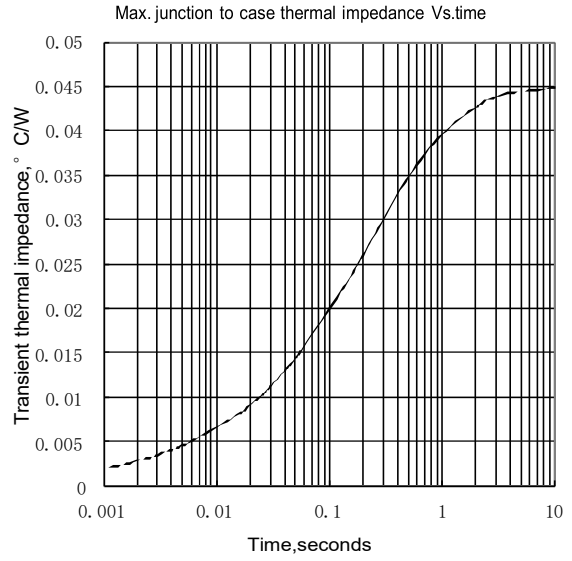


Fig2

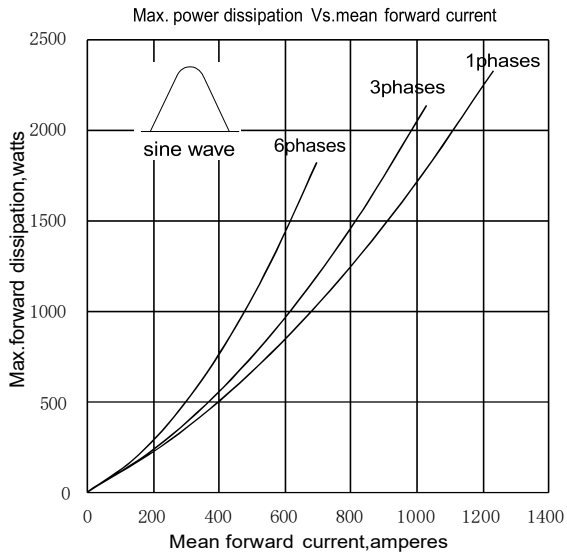


Fig3

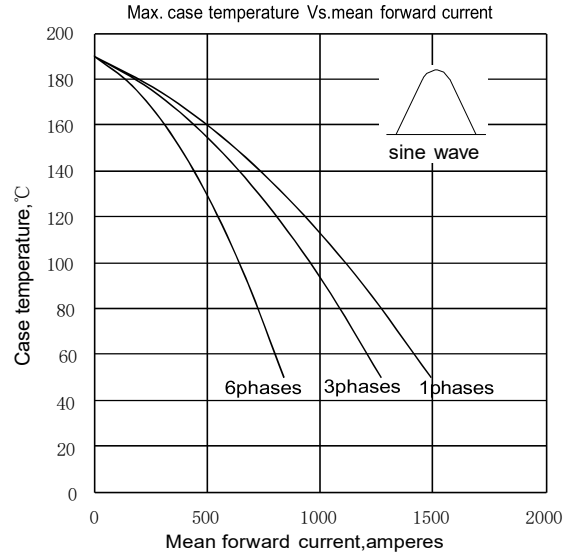


Fig4

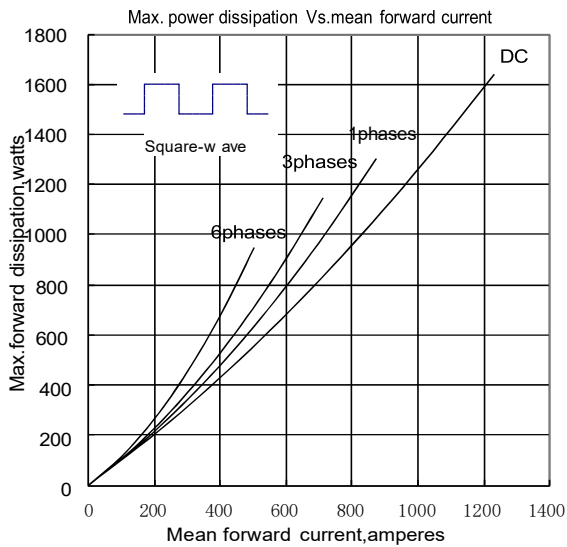


Fig5

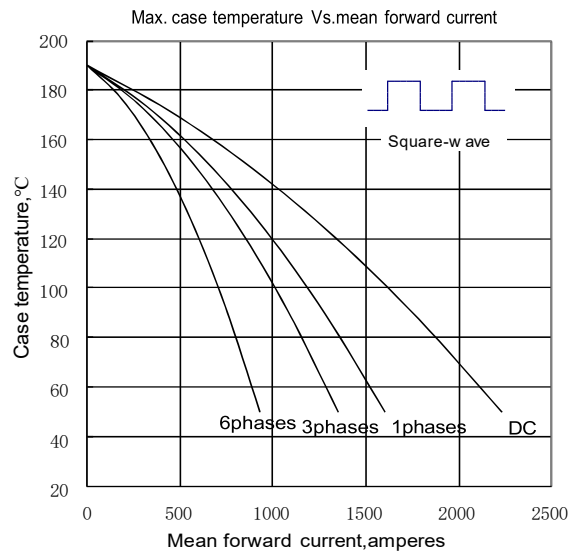


Fig6

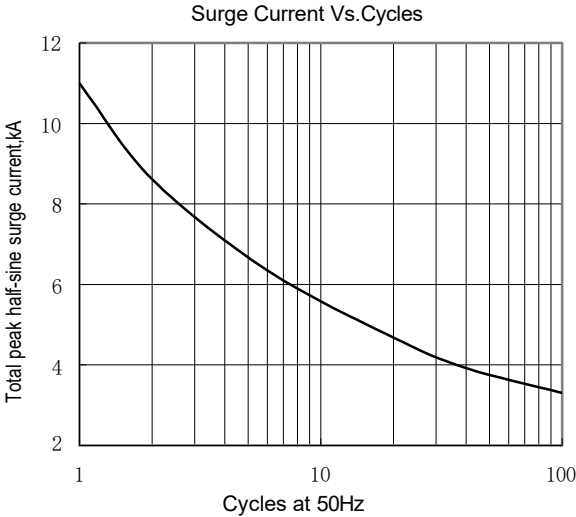


Fig.7

Outline:

